

# **Schottky Barrier Power Rectifiers**

Using the Schottky Barrier principle with a Molybdenum barrier metal. These state-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes.

#### **Features**

- \* Low Forward Voltage.
- \* Low Switching noise.
- \* High Current Capacity
- \* Guarantee Reverse Avalanche.
- \* Guard-Ring for Stress Protection.
- \* Low Power Loss & High efficiency.
- \* 150 Operating Junction Temperature
- \* Low Stored Charge Majority Carrier Conduction.
- \* Plastic Material used Carries Underwriters Laboratory
- \* ESD: 4KV(Min.) Human-Body Model



\* In compliance with EU RoHs 2002/95/EC directives

## **MAXIMUM RATINGS**

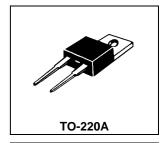
Characteristic	Symbol	S10A70	S10A80	S10A90	S10A100	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	70	80	90	100	V
RMS Reverse Voltage	V <sub>R(RMS)</sub>	49	56	63	70	V
Average Rectifier Forward Current	I <sub>F(AV)</sub>	10			Α	
Peak Repetitive Forward Current (Rate V <sub>R</sub> , Square Wave, 20kHz)	I <sub>FM</sub>	10			Α	
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	I <sub>FSM</sub>	200		Α		
Operating and Storage Junction Temperature Range	$T_J,T_STG$	-65 to +150				

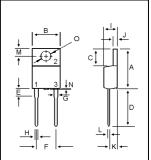
## **ELECTRIAL CHARACTERISTICS**

Characteristic	Symbol	S10A70	S10A80	S10A90	S10A100	Unit
Maximum Instantaneous Forward Voltage ( $I_F = 10 \text{ Amp } T_C = 25$ ) ( $I_F = 10 \text{ Amp } T_C = 125$ )	V <sub>F</sub>	0.° 0.			85 76	V
Typical Thermal Resistance junction to case	R <sub>θ j-c</sub>	3.4			/w	
Maximum Instantaneous Reverse Current ( Rated DC Voltage, $T_C = 25$ ) ( Rated DC Voltage, $T_C = 125$ )	I <sub>R</sub>	0.2 20		mA		

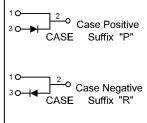
#### SCHOTTKY BARRIER RECTIFIERS

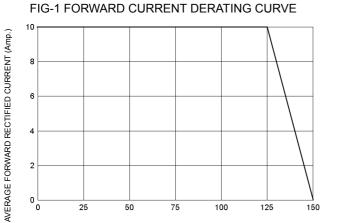
10 AMPERES 70-100 VOLTS





DIM	MILLIMETERS			
DIIVI	MIN	MAX		
Α	14.68	15.32		
В	9.78	10.42		
С	6.02	6.52		
D	13.06	14.62		
E	3.57	4.07		
F	4.84	5.32		
G	1.12	1.36		
Н	0.72	0.96		
- 1	4.22	4.98		
J	1.14	1.38		
K	2.20	2.98		
L	0.33	0.55		
M	2.48	2.98		
N		1.00		
0	3.70	3.90		



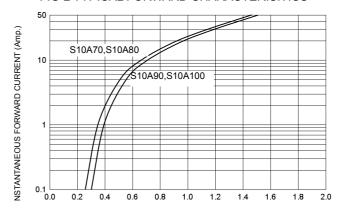


CASE TEMPERATURE ( )

125

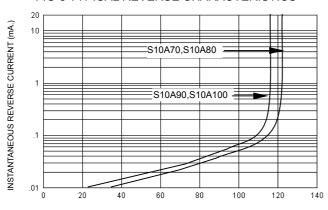
150

### FIG-2 TYPICAL FORWARD CHARACTERISITICS



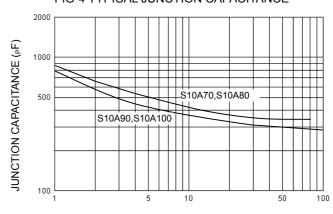
FORWARD VOLTAGE (Volts)

#### FIG-3 TYPICAL REVERSE CHARACTERISTICS



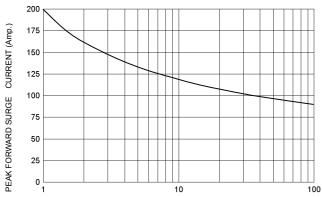
PERCENT OF RATED REVERSE VOLTAGE (%)

## FIG-4 TYPICAL JUNCTION CAPACITANCE



REVERSE VOLTAGE (Volts)





NUMBER OF CYCLES AT 60 Hz



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